



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C
-50V	$8\Omega @ V_{GS} = -5V$	X1-DFN1006-3	-310mA

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected 1kV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

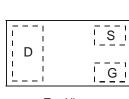
- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.001 grams (Approximate)



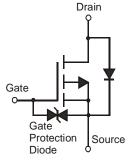




Bottom View



Top View Pin-Out



Equivalent Circuit

Ordering Information (Note 4)

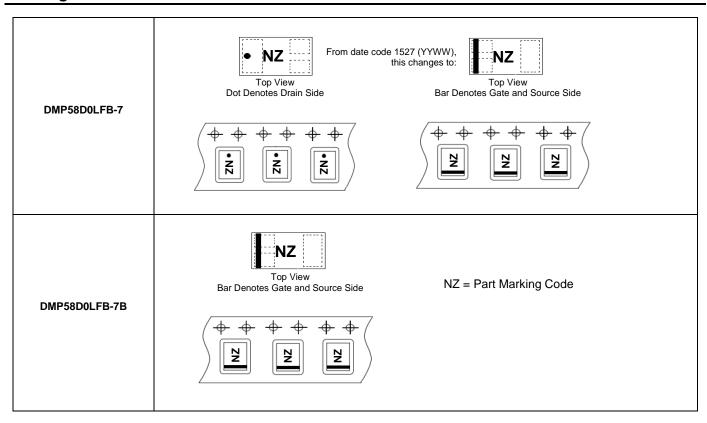
Part Number	Case	Packaging
DMP58D0LFB-7	X1-DFN1006-3	3,000 / Tape & Reel
DMP58D0LFB-7B	X1-DFN1006-3	10,000 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



Character	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-50	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 5) V _{GS} = -5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-180 -150	mA
Continuous Drain Current (Note 5) $V_{GS} = -5V$ Steady $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			I _D	-310 -250	mA
Pulsed Drain Current (Note 7)	I _{DM}	-500	mA		

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 5)	P_{D}	0.47	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	258	°C/W
Power Dissipation (Note 6)	P_{D}	1.22	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	$R_{\theta JA}$	105	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

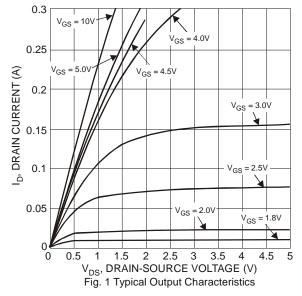
Characteristic		Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage		-50	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-1.0	μA	$V_{DS} = -50V, V_{GS} = 0V$
Gate-Source Leakage		_	_	±5	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(th)}	-0.8	_	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	<u> </u>	_	6	8	Ω	$V_{GS} = -5V, I_D = -100mA$
Static Drain-Source On-Resistance	R _{DS} (ON)	_	12	18	Ω	$V_{GS} = -2.5V, I_D = -10mA$
Forward Transfer Admittance	Y _{fs}	0.05	_	_	S	$V_{DS} = -25V, I_{D} = -100mA$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	_	27	_		251/1/
Output Capacitance	Coss	_	4.0	_	pF	$V_{DS} = -25V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	1.4	_		
Turn-On Delay Time	t _{D(on)}	_	30.7	_		
Turn-On Rise Time	t _r	_	84.1	_		$V_{GS} = -4.5V, V_{DS} = -30V,$
Turn-Off Delay Time	t _{D(off)}	_	201.8	_	ns	$R_G = 50\Omega$, $I_D = -10$ mA
Turn-Off Fall Time	t _f	_	32.2	_		

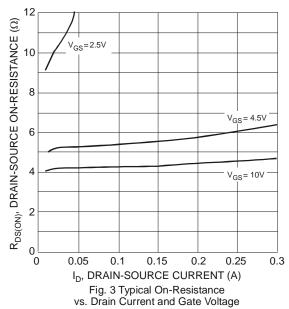
Notes:

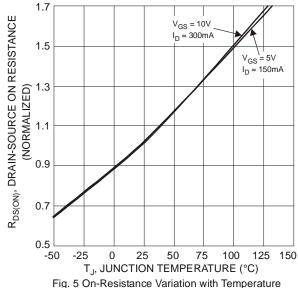
- $5. \ \, \text{Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. }$
- Device mounted on FR-4 substrate PC board, 2oz copper, with himmum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate
 Repetitive rating, pulse width limited by junction temperature.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.

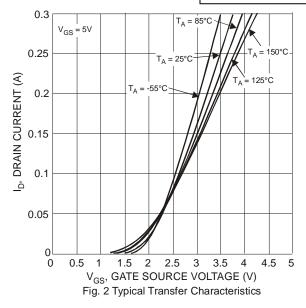


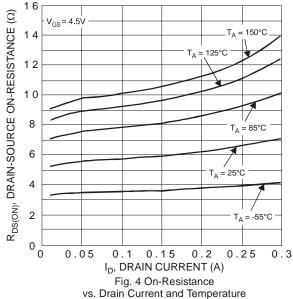


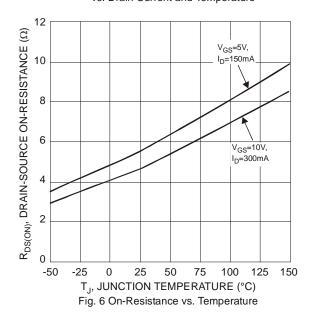












DMP58D0LFB

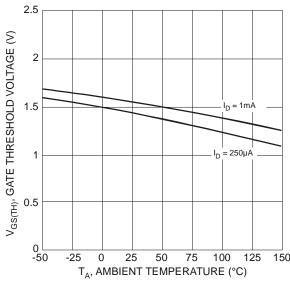


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

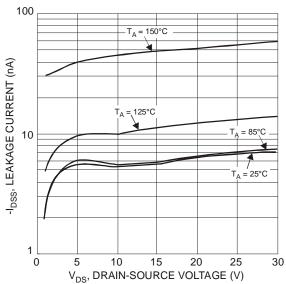
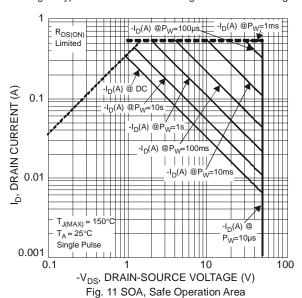
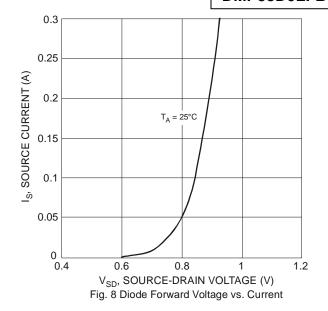
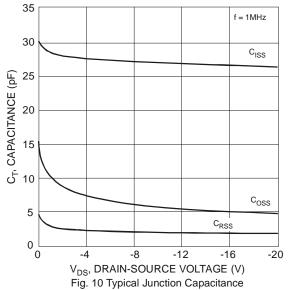


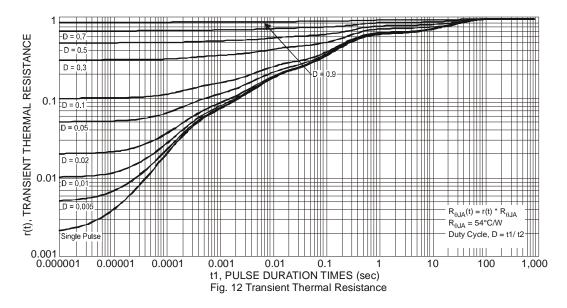
Fig. 9 Typical Drain-Source Leakage Current vs. Voltage





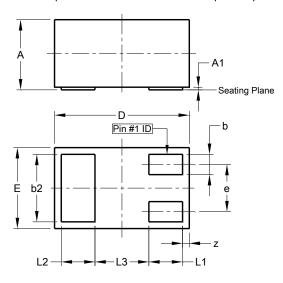






Package Outline Dimensions

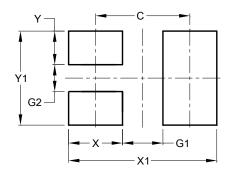
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X1-DFN1006-3					
Dim	Min	Max	Тур		
Α	0.47	0.53	0.50		
A1	0.00	0.05	0.03		
b	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Е	0.55	0.675	0.60		
е	-	-	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
L3	-	-	0.40		
Z	0.02	0.08	0.05		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	0.70		
G1	0.30		
G2	0.20		
Х	0.40		
X1	1.10		
Y	0.25		
Y1	0.70		



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